74LVC540A

Low-Voltage CMOS Octal Buffer Flow Through Pinout

With 5 V−Tolerant Inputs and Outputs (3−State, Inverting)

The 74LVC540A is a high performance, inverting octal buffer operating from a 1.2 to 3.6 V supply. This device is similar in function to the MC74LCX240, while providing flow through architecture. High impedance TTL compatible inputs significantly reduce current loading to input drivers while TTL compatible outputs offer improved switching noise performance. A V_I specification of 5.5 V allows 74LVC540A inputs to be safely driven from 5 V devices. The 74LVC540A is suitable for memory address driving and all TTL level bus oriented transceiver applications.

Current drive capability is 24 mA at the outputs. The Output Enable ($\overline{OE1}$, $\overline{OE2}$) inputs, when HIGH, disables the outputs by placing them in a HIGH Z condition.

Features

- Designed for 1.2 to 3.6 V V_{CC} Operation
- 5 V Tolerant − Interface Capability With 5 V TTL Logic
- Supports Live Insertion and Withdrawal
- I_{OFF} Specification Guarantees High Impedance When V_{CC} = 0 V
- 24 mA Output Sink and Source Capability
- Near Zero Static Supply Current in All Three Logic States (10 μA) Substantially Reduces System Power Requirements
- Latchup Performance Exceeds 250 mA
- ESD Performance:
  - Human Body Model > 2000 V
  - Machine Model > 200 V
- These Devices are Pb−Free, Halogen Free/BFR Free and are RoHS Compliant

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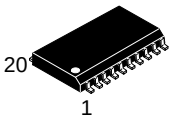
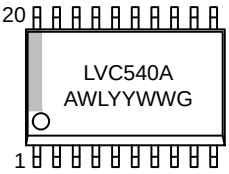
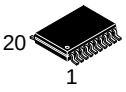
MARKING DIAGRAMS

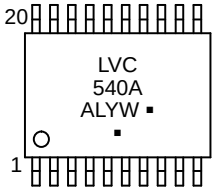


SOIC−20 WB
DW SUFFIX
CASE 751D





TSSOP−20
DT SUFFIX
CASE 948E



A	= Assembly Location
L, WL	= Wafer Lot
Y, YY	= Year
W, WW	= Work Week
G or ▪	= Pb−Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.

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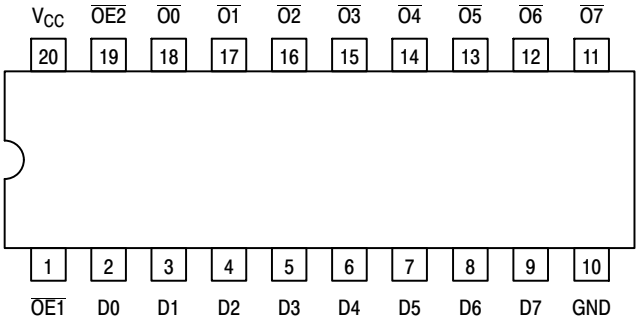


Figure 1. Pinout: 20−Lead (Top View)

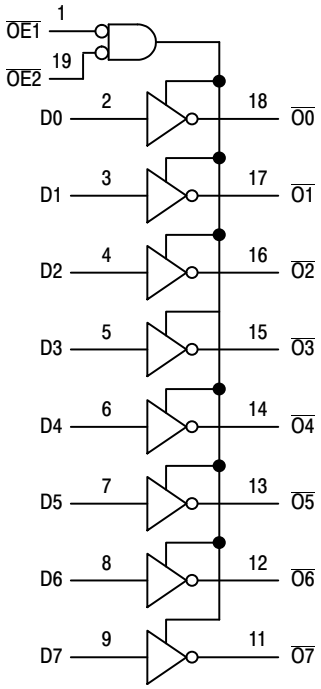


Figure 2. Logic Diagram

PIN NAMES

Pins	Function
$\overline{OEn}$	Output Enable Inputs
Dn	Data Inputs
$\overline{On}$	3−State Outputs

TRUTH TABLE

Inputs			Outputs
$\overline{OE1}$	$\overline{OE2}$	Dn	$\overline{On}$
L	L	L	H
L	L	H	L
X	H	X	Z
H	X	X	Z

H = High Voltage Level
L = Low Voltage Level
Z = High Impedance State
X = High or Low Voltage Level and Transitions are Acceptable
For I_{CC} reasons, DO NOT FLOAT Inputs

MAXIMUM RATINGS

Symbol	Parameter	Value	Condition	Unit
V_{CC}	DC Supply Voltage	−0.5 to +6.5		V
V_I	DC Input Voltage	$-0.5 \le V_I \le +6.5$		V
V_O	DC Output Voltage	$-0.5 \le V_O \le +6.5$	Output in 3−State	V
		$-0.5 \le V_O \le V_{CC} + 0.5$	Output in HIGH or LOW State (Note 1)	V
I_{IK}	DC Input Diode Current	−50	$V_I < GND$	mA
I_{OK}	DC Output Diode Current	−50	$V_O < GND$	mA
		+50	$V_O > V_{CC}$	mA
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current Per Supply Pin	±100		mA
I_{GND}	DC Ground Current Per Ground Pin	±100		mA
T_{STG}	Storage Temperature Range	−65 to +150		°C
T_L	Lead Temperature, 1 mm from Case for 10 Seconds	T_L = 260		°C
T_J	Junction Temperature Under Bias	T_J = 135		°C
θ_{JA}	Thermal Resistance (Note 2)	SOIC = 65.8 TSSOP = 110.7		°C/W
MSL	Moisture Sensitivity		Level 1	
$I_{LATCHUP}$	Latch−up Performance at V_{CC} = 3.6 V and 125°C (Note 3)		±250	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. I_O absolute maximum rating must be observed.
2. Measured with minimum pad spacing on an FR4 board, using 10 mm−by−1 inch, 2 ounce copper trace no air flow.
3. Tested to EIA/JES078.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Typ	Max	Units
V_{CC}	Supply Voltage Operating Functional	 1.65 1.2		 3.6 3.6	V
V_I	Input Voltage	0		5.5	V
V_O	Output Voltage HIGH or LOW State 3−State	 0 0		 V_{CC} 5.5	V
I_{OH}	HIGH Level Output Current V_{CC} = 3.0 V − 3.6 V V_{CC} = 2.7 V − 3.0 V			 −24 −12	mA
I_{OL}	LOW Level Output Current V_{CC} = 3.0 V − 3.6 V V_{CC} = 2.7 V − 3.0 V			 24 12	mA
T_A	Operating Free−Air Temperature	−40		+125	°C
$\Delta t/\Delta V$	Input Transition Rise or Fall Rate, V_{IN} from 0.8 V to 2.0 V, V_{CC} = 3.0 V	0		10	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Conditions	−40°C to +85°C			−40°C to +125°C			Unit
			Min	Typ (Note 4)	Max	Min	Typ (Note 4)	Max	
V_{IH}	HIGH−level input voltage	V_{CC} = 1.2 V	1.08	−	−	1.08	−	−	V
		V_{CC} = 1.65 V to 1.95 V	0.65 x V_{CC}	−	−	0.65 x V_{CC}	−	−	
		V_{CC} = 2.3 V to 2.7 V	1.7	−	−	1.7	−	−	
		V_{CC} = 2.7 V to 3.6 V	2.0	−	−	2.0	−	−	
V_{IL}	LOW−level input voltage	V_{CC} = 1.2 V	−	−	0.12	−	−	0.12	V
		V_{CC} = 1.65 V to 1.95 V	−	−	0.35 x V_{CC}	−	−	0.35 x V_{CC}	
		V_{CC} = 2.3 V to 2.7 V	−	−	0.7	−	−	0.7	
		V_{CC} = 2.7 V to 3.6 V	−	−	0.8	−	−	0.8	
V_{OH}	HIGH−level output voltage	V_I = V_{IH} or V_{IL}							V
		I_O = −100 μA; V_{CC} = 1.65 V to 3.6 V	V_{CC} − 0.2	−	−	V_{CC} − 0.3	−	−	
		I_O = −4 mA; V_{CC} = 1.65 V	1.2	−	−	1.05	−	−	
		I_O = −8 mA; V_{CC} = 2.3 V	1.8	−	−	1.65	−	−	
		I_O = −12 mA; V_{CC} = 2.7 V	2.2	−	−	2.05	−	−	
		I_O = −18 mA; V_{CC} = 3.0 V	2.4	−	−	2.25	−	−	
		I_O = −24 mA; V_{CC} = 3.0 V	2.2	−	−	2.0	−	−	
V_{OL}	LOW−level output voltage	V_I = V_{IH} or V_{IL}							V
		I_O = 100 μA; V_{CC} = 1.65 V to 3.6 V	−	−	0.2	−	−	0.3	
		I_O = 4 mA; V_{CC} = 1.65 V	−	−	0.45	−	−	0.65	
		I_O = 8 mA; V_{CC} = 2.3 V	−	−	0.6	−	−	0.8	
		I_O = 12 mA; V_{CC} = 2.7 V	−	−	0.4	−	−	0.6	
		I_O = −24 mA; V_{CC} = 3.0 V	−	−	0.55	−	−	0.8	
I_I	Input leakage current	V_I = 5.5V or GND V_{CC} = 3.6 V	−	±0.1	±5	−	±0.1	±20	μA
I_{OZ}	OFF−state output current	VI = VIH or VIL; V_O = 5.5 V or GND; V_{CC} = 3.6 V	−	±0.1	±5	−	±0.1	±20	μA
I_{OFF}	Power−off leakage current	V_I or V_O = 5.5 V; V_{CC} = 0.0 V	−	±0.1	±10	−	±0.1	±20	μA
I_{CC}	Supply current	V_I = V_{CC} or GND; I_O = 0 A; V_{CC} = 3.6 V	−	0.1	10	−	0.1	40	μA
ΔI_{CC}	Additional supply current	per input pin; V_I = V_{CC} − 0.6 V; I_O = 0 A; V_{CC} = 2.7 V to 3.6 V	−	5	500	−	5	5000	μA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

4. All typical values are measured at T_A = 25°C and V_{CC} = 3.3 V, unless stated otherwise.

AC ELECTRICAL CHARACTERISTICS ($t_R = t_F$ = 2.5 ns)

Symbol	Parameter	Conditions	−40°C to +85°C			−40°C to +125°C			Unit
			Min	Typ[5]	Max	Min	Typ[5]	Max	
t_{pd}	Propagation Delay (Note 6) nDn to n$\overline{O}$n	V_{CC} = 1.2 V	−	18.0	−	−	−	−	ns
		V_{CC} = 1.65 V to 1.95 V	1.0	−	16.4	1.0	−	16.4	
		V_{CC} = 2.3 V to 2.7 V	1.0	−	7.8	1.0	−	7.8	
		V_{CC} = 2.7 V	1.0	−	7.1	1.0	−	7.1	
		V_{CC} = 3.0 V to 3.6 V	1.0	−	5.3	1.0	−	5.3	
t_{en}	Enable Time (Note 7) n$\overline{OE}$ to n$\overline{O}$n	V_{CC} = 1.2 V	−	20.0	−	−	−	−	ns
		V_{CC} = 1.65 V to 1.95 V	1.0	−	16.5	1.0	−	16.5	
		V_{CC} = 2.3 V to 2.7 V	1.0	−	10.5	1.0	−	10.5	
		V_{CC} = 2.7 V	1.0	−	8.0	1.0	−	8.0	
		V_{CC} = 3.0 V to 3.6 V	1.0	−	6.6	1.0	−	6.6	
t_{dis}	Disable Time (Note 8) n$\overline{OE}$ to n$\overline{O}$n	V_{CC} = 1.2 V	−	18.0	−	−	−	−	ns
		V_{CC} = 1.65 V to 1.95 V	1.0	−	15.9	1.0	−	15.9	
		V_{CC} = 2.3 V to 2.7 V	1.0	−	9.0	1.0	−	9.0	
		V_{CC} = 2.7 V	1.0	−	8.2	1.0	−	8.2	
		V_{CC} = 3.0 V to 3.6 V	1.0	−	7.4	1.0	−	7.4	
$t_{sk(0)}$	Output Skew Time (Note 9)		−	−	1.0	−	−	1.5	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

5. Typical values are measured at T_A = 25°C and V_{CC} = 3.3 V, unless stated otherwise.
6. t_{pd} is the same as t_{PLH} and t_{PHL}.
7. t_{en} is the same as t_{PZL} and t_{PZH}.
8. t_{dis} is the same as t_{PLZ} and t_{PHZ}.
9. Skew between any two outputs of the same package switching in the same direction. This parameter is guaranteed by design.

DYNAMIC SWITCHING CHARACTERISTICS

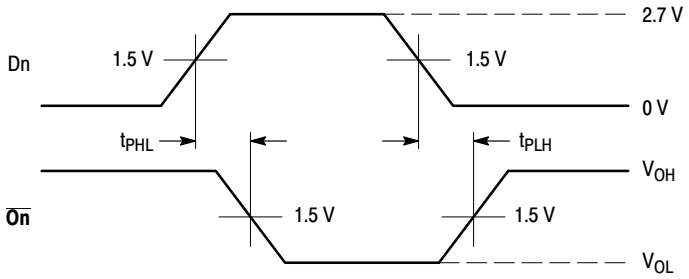
Symbol	Characteristic	Condition	T_A = +25°C			Unit
			Min	Typ	Max	
V_{OLP}	Dynamic LOW Peak Voltage (Note 10)	V_{CC} = 3.3 V, C_L = 50 pF, V_{IH} = 3.3 V, V_{IL} = 0 V V_{CC} = 2.5 V, C_L = 30 pF, V_{IH} = 2.5 V, V_{IL} = 0 V		0.8 0.6		V
V_{OLV}	Dynamic LOW Valley Voltage (Note 10)	V_{CC} = 3.3 V, C_L = 50 pF, V_{IH} = 3.3 V, V_{IL} = 0 V V_{CC} = 2.5 V, C_L = 30 pF, V_{IH} = 2.5 V, V_{IL} = 0 V		−0.8 −0.6		V

10. Number of outputs defined as “n”. Measured with “n−1” outputs switching from HIGH−to−LOW or LOW−to−HIGH. The remaining output is measured in the LOW state.

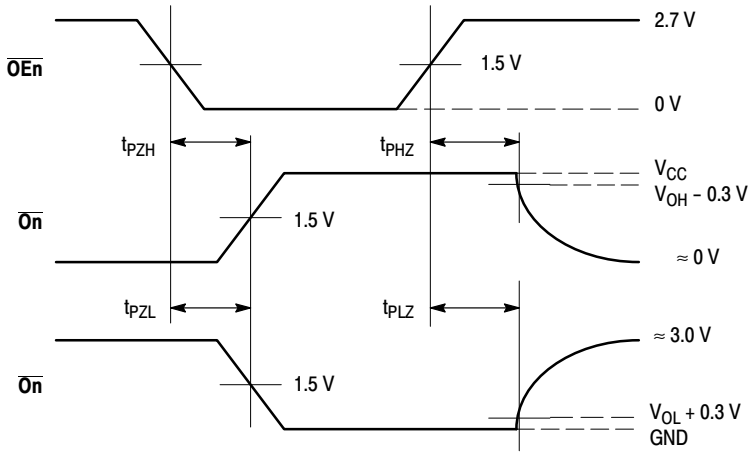
CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Condition	Typical	Unit
C_{IN}	Input Capacitance	V_{CC} = 3.3 V, V_I = 0 V or V_{CC}	5.0	pF
C_{OUT}	Output Capacitance	V_{CC} = 3.3 V, V_I = 0 V or V_{CC}	7.0	pF
C_{PD}	Power Dissipation Capacitance (Note 11)	Per input; V_I = GND or V_{CC}		pF
		V_{CC} = 1.65 V to 1.95 V	7.7	
		V_{CC} = 2.3 V to 2.7 V	11.3	
		V_{CC} = 3.0 V to 3.6 V	14.4	

11. C_{PD} is used to determine the dynamic power dissipation (P_D in μW).
$P_D = C_{PD} * V_{CC}^2 \times fi * N + \Sigma (C_L \times V_{CC}^2 \times fo)$ where:
fi = input frequency in MHz; fo = output frequency in MHz
C_L = output load capacitance in pF V_{CC} = supply voltage in Volts
N = number of outputs switching
$\Sigma(C_L * V_{CC}^2 \times fo)$ = sum of the outputs.



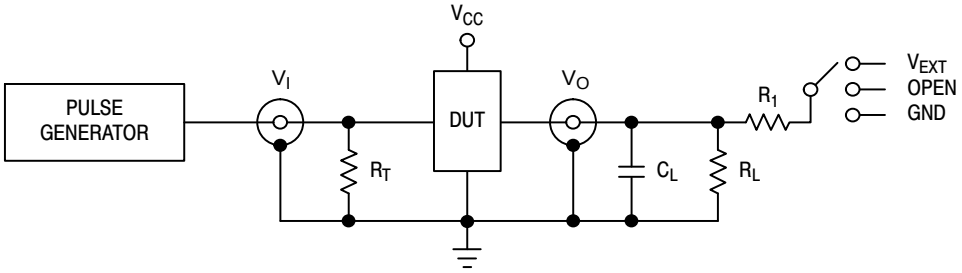
WAVEFORM 1 – PROPAGATION DELAYS
$t_R = t_F$ = 2.5 ns, 10% to 90%; f = 1 MHz; t_W = 500 ns



WAVEFORM 2 – OUTPUT ENABLE AND DISABLE TIMES
$t_R = t_F$ = 2.5 ns, 10% to 90%; f = 1 MHz; t_W = 500 ns

Figure 3. AC Waveforms

	V_{CC}		
Symbol	**3.3 V ± 0.3 V**	**2.7 V**	**V_{CC} < 2.7 V**
Vmi	1.5 V	1.5 V	$V_{CC}/2$
Vmo	1.5 V	1.5 V	$V_{CC}/2$
V_{HZ}	V_{OL} + 0.3 V	V_{OL} + 0.3 V	V_{OL} + 0.15 V
V_{LZ}	V_{OH} − 0.3 V	V_{OH} − 0.3 V	V_{OH} − 015 V



C_L includes jig and probe capacitance
$R_T = Z_{OUT}$ of pulse generator (typically 50 Ω)
$R_1 = R_L$

Supply Voltage	Input		Load		V_{EXT}		
V_{CC} (V)	V_I	t_r, t_f	C_L	R_L	t_{PLH}, t_{PHL}	t_{PLZ}, t_{PZL}	t_{PHZ}, t_{PZH}
1.2	V_{CC}	≤ 2 ns	30 pF	1 kΩ	Open	2 x V_{CC}	GND
1.65 − 1.95	V_{CC}	≤ 2 ns	30 pF	1 kΩ	Open	2 x V_{CC}	GND
2.3 − 2.7	V_{CC}	≤ 2 ns	30 pF	500 Ω	Open	2 x V_{CC}	GND
2.7	2.7 V	≤ 2.5 ns	50 pF	500 Ω	Open	2 x V_{CC}	GND
3 − 3.6	2.7 V	≤ 2.5 ns	50 pF	500 Ω	Open	2 x V_{CC}	GND

Figure 4. Test Circuit

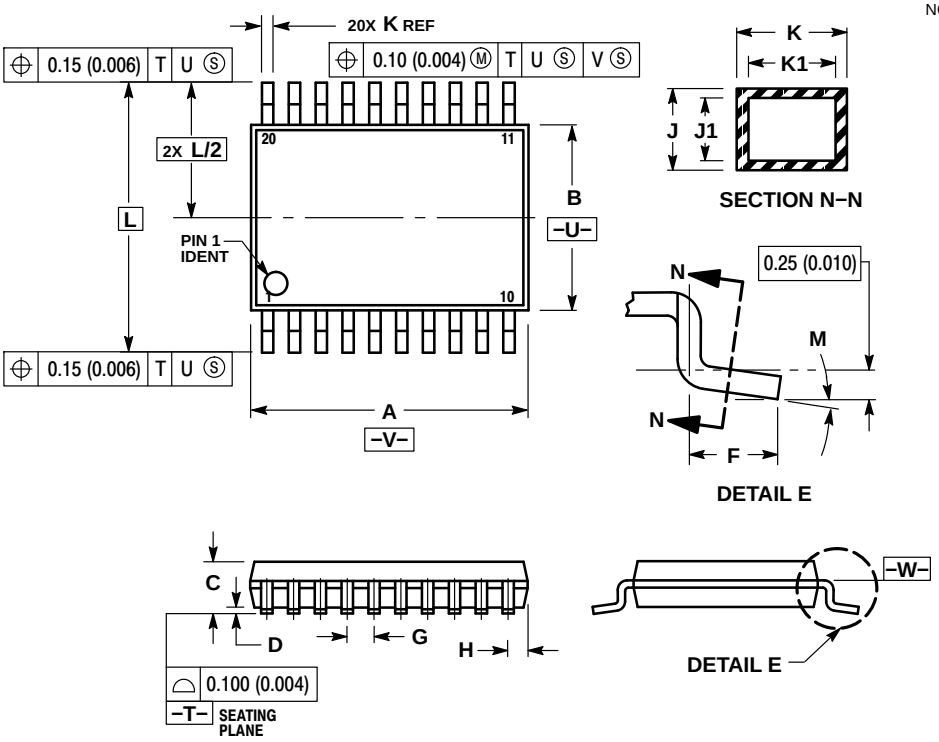
ORDERING INFORMATION

Device	Package	Shipping†
74LVC540ADWR2G	SOIC−20 (Pb−Free)	1000 / Tape & Reel
74LVC540ADTR2G	TSSOP−20 (Pb−Free)	2500 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

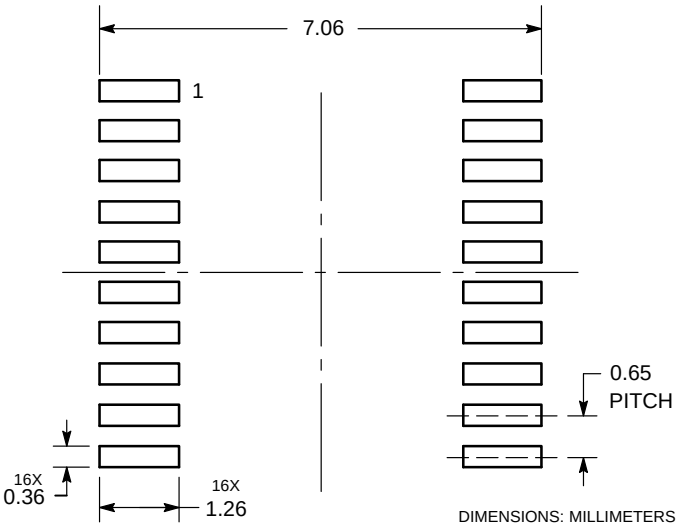
TSSOP−20
CASE 948E−02
ISSUE C



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE −W−.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	6.40	6.60	0.252	0.260
B	4.30	4.50	0.169	0.177
C	---	1.20	---	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
H	0.27	0.37	0.011	0.015
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0°	8°	0°	8°

SOLDERING FOOTPRINT*

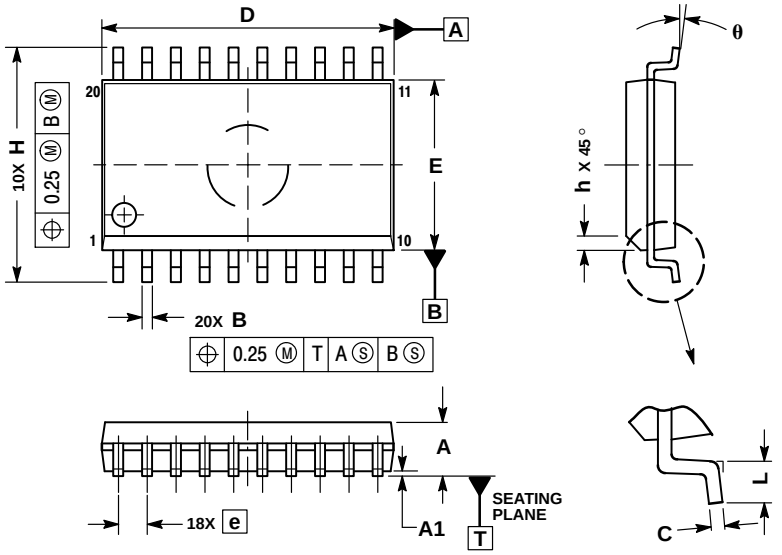


DIMENSIONS: MILLIMETERS

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

SOIC−20 WB
CASE 751D−05
ISSUE G



NOTES:
1. DIMENSIONS ARE IN MILLIMETERS.
2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS	
DIM	MIN	MAX
A	2.35	2.65
A1	0.10	0.25
B	0.35	0.49
C	0.23	0.32
D	12.65	12.95
E	7.40	7.60
e	1.27 BSC	
H	10.05	10.55
h	0.25	0.75
L	0.50	0.90
θ	0°	7°

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Поставка электронных компонентов

Компания «Океан Электроники» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Поставка оригинальных импортных электронных компонентов напрямую с производств Америки, Европы и Азии, а так же с крупнейших складов мира;
- Широкая линейка поставок активных и пассивных импортных электронных компонентов (более 30 млн. наименований);
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Компания «Океан Электроники» является официальным дистрибьютором и эксклюзивным представителем в России одного из крупнейших производителей разъемов военного и аэрокосмического назначения «**JONHON**», а так же официальным дистрибьютором и эксклюзивным представителем в России производителя высокотехнологичных и надежных решений для передачи СВЧ сигналов «**FORSTAR**».

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(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).

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Web: http://oceanchips.ru/
Адрес: 198099, г. Санкт-Петербург, ул. Калинина, д. 2, корп. 4, лит. А